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Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China







Product data sheet

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NXP Semiconductors



Silicon PIN diode BAP63-02

FEATURES

- High speed switching for RF signals
- Low diode capacitance
- Low diode forward resistance
- Very low series inductance
- For applications up to 3 GHz.

APPLICATIONS

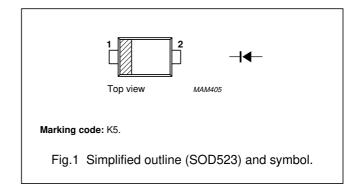
• RF attenuators and switches.

DESCRIPTION

Planar PIN diode in a SOD523 ultra small SMD plastic package.

PINNING

| PIN | DESCRIPTION | |
|-----|-------------|--|
| 1 | cathode | |
| 2 | anode | |



LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|------------------|----------------------------|------------------------|-----------------|------|------|
| V _R | continuous reverse voltage | | _ | 50 | ٧ |
| I _F | continuous forward current | | _ | 100 | mA |
| P _{tot} | total power dissipation | T _s ≤ 90 °C | _ | 715 | mW |
| T _{stg} | storage temperature | | - 65 | +150 | °C |
| Tj | junction temperature | | -65 | +150 | °C |

Silicon PIN diode BAP63-02

ELECTRICAL CHARACTERISTICS

 $T_i = 25$ °C unless otherwise specified.

| SYMBOL PARAMETER CONDITIONS | | TYP. | MAX. | UNIT | | |
|--------------------------------|--------------------------|---|------|------|----|--|
| V _F | forward voltage | I _F = 50 mA | 0.95 | 1.1 | ٧ | |
| I _R | reverse leakage current | V _R = 35 V | _ | 10 | nA | |
| C _d | diode capacitance | V _R = 0; f = 1 MHz | 0.36 | _ | pF | |
| - | | V _R = 1 V; f = 1 MHz | 0.32 | _ | pF | |
| | | V _R = 20 V; f = 1 MHz | 0.25 | 0.32 | pF | |
| r _D | diode forward resistance | I _F = 0.5 mA; f = 100 MHz; note 1 | 2.5 | 3.5 | Ω | |
| | | I _F = 1 mA; f = 100 MHz; note 1 | 1.95 | 3 | Ω | |
| | | I _F = 10 mA; f = 100 MHz; note 1 | 1.17 | 1.8 | Ω | |
| | | $I_F = 100 \text{ mA}$; $f = 100 \text{ MHz}$; note 1 | 0.9 | 1.5 | Ω | |
| S ₂₁ ² | isolation | V _R = 0; f = 900 MHz | 15.6 | _ | dB | |
| | | V _R = 0; f = 1800 MHz | 10.3 | _ | dB | |
| | | V _R = 0; f = 2450 MHz | 8.3 | _ | dB | |
| s ₂₁ ² | insertion loss | I _F = 0.5 mA; f = 900 MHz | 0.19 | _ | dB | |
| | | I _F = 0.5 mA; f = 1800 MHz | 0.24 | _ | dB | |
| | | I _F = 0.5 mA; f = 2450 MHz | 0.28 | _ | dB | |
| S ₂₁ ² | insertion loss | I _F = 1 mA; f = 900 MHz | 0.16 | _ | dB | |
| | | I _F = 1 mA; f = 1800 MHz | 0.20 | _ | dB | |
| | | I _F = 1 mA; f = 2450 MHz | 0.25 | _ | dB | |
| S ₂₁ ² | insertion loss | I _F = 10 mA; f = 900 MHz | 0.10 | _ | dB | |
| | | I _F = 10 mA; f = 1800 MHz | 0.16 | _ | dB | |
| | | I _F = 10 mA; f = 2450 MHz | 0.20 | _ | dB | |
| S ₂₁ ² | insertion loss | I _F = 100 mA; f = 900 MHz | 0.09 | _ | dB | |
| | | I _F = 100 mA; f = 1800 MHz | 0.14 | _ | dB | |
| | | I _F = 100 mA; f = 2450 MHz | 0.18 | _ | dB | |
| τ∟ | charge carrier life time | when switched from I $_F$ = 10 mA to I $_R$ = 6 mA; R $_L$ = 100 Ω ; measured at I $_R$ = 3 mA | 310 | _ | ns | |
| L _S | series inductance | I _F = 100 mA; f = 100 MHz | 0.6 | _ | nH | |

Note

THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | VALUE | UNIT |
|---------------------|---|-------|------|
| R _{th j-s} | thermal resistance from junction to soldering point | 85 | K/W |

^{1.} Guaranteed on AQL basis: inspection level S4, AQL 1.0.

Silicon PIN diode BAP63-02

GRAPHICAL DATA

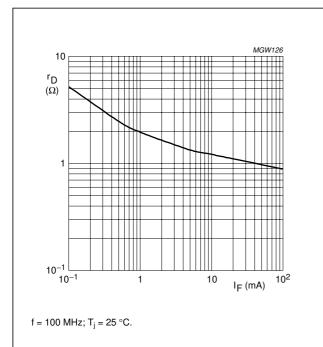


Fig.2 Forward resistance as a function of forward current; typical values.

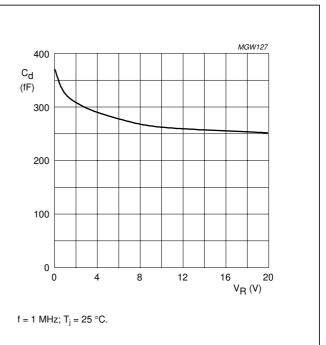
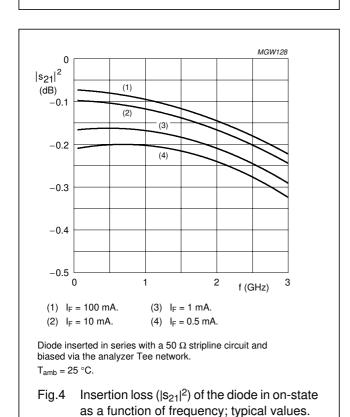
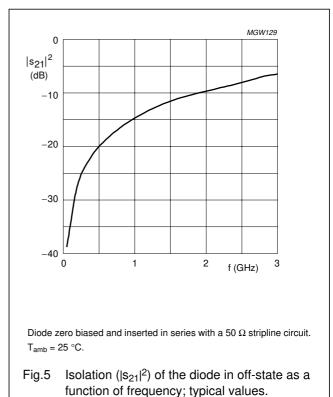


Fig.3 Diode capacitance as a function of reverse voltage; typical values.



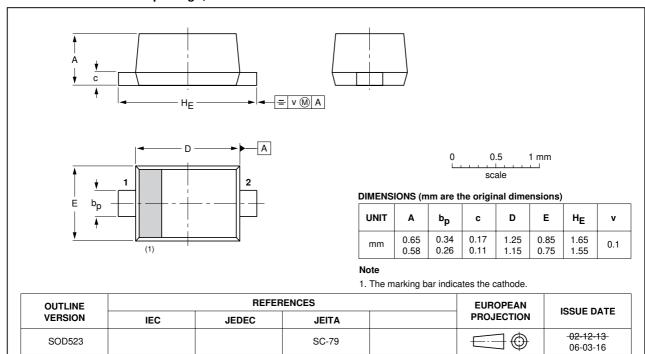


Silicon PIN diode BAP63-02

PACKAGE OUTLINE

Plastic surface-mounted package; 2 leads

SOD523



NXP Semiconductors BAP63-02

Silicon PIN diode

Legal information

Data sheet status

| Document status[1][2] | Product status[3] | Definition |
|--------------------------------|-------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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NXP Semiconductors BAP63-02

Silicon PIN diode

Revision history

Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|---|--------------|---------------------------|---------------|--------------|
| BAP63-02_N_4 | 20080108 | Product data sheet | - | BAP63-02_3 |
| Modifications: • Package outline drawing on page 5 changed | | | | |
| BAP63-02_3 (9397 750 08261) | 20010518 | Product specification | - | BAP63-02_N_2 |
| BAP63-02_N_2 (9397 750 08141) | 20010320 | Preliminary specification | - | BAP63-02_N_1 |
| BAP63-02_N_1 (9397 750 08051) | 20010220 | Preliminary specification | - | - |

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